

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application No.: 10/780,031 Confirmation No.: 9275
First Named Inventor: Park, Jongmin Filing Date: 17 February 2004
Group Art Unit: 2824 Examiner: Wendler, Eric J.
Atty. Docket No.: R-0003 US
Title: Technique for Programming Floating-gate Transistor Used in
Circuitry Such as Flash EPROM
Assignee(s): ProMOS Technologies Inc.

Mountain View, California
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AMENDMENT TO TEXT UNDER 37 CFR 1.312

Sir:

Responsive to the Notice of Allowance mailed 19 April 2006 and under the provisions of 37 CFR 1.312, please amend the above patent application in the following manner.

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OK to
enter.
8/4/06
EJW